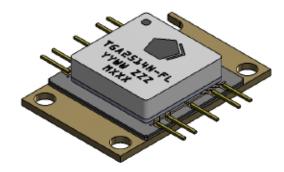
Product Description

Qorvo's TGA2514N-FL is a packaged Ku-band power amplifier operating from 13–16 GHz. Fabricated on Qorvo's production 0.25 um GaAs pHEMT process (QPHT25), the TGA2514N–FL delivers 6.5 W of saturated output power with 24 dB of small signal gain. Performance is ideal for VSAT transmitters, data links and point to point radios.

To support easy system integration, the TGA2514N–FL is offered in a 10-pin flange–mounted package, offering robust handling and good thermal management. In addition, both RF ports have integrated DC blocking capacitors and are fully matched to 50 ohms.

Lead free and RoHS compliant.

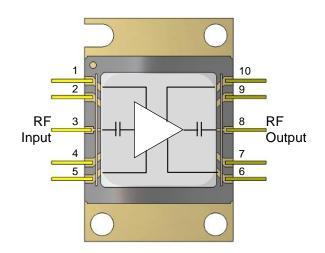
TGA2514N-FL 13 – 18 GHz Power Amplifier



Product Features

- Frequency Range: 13-16 GHz
- Saturated Output Power: 38 dBm
- Small Signal Gain: 24 dB
- Input and Output Return Loss: 14 dB
- Bias Condition (VD/IDQ): 8.0V/2.6 A
- Package Size: 0.448 x 0.682 x 0.120 inches (11.379 x 17.323 x 3.048 mm)

Performance is typical across frequency. Please reference electrical specification table and data plots for more details



Functional Block Diagram

Applications

- Ku Band VSAT Transmitter
- Point to Point Radio

Ordering Information

Part No.	Description
TGA2514N-FL	13–16 GHz Power Amplifier
1127039	Evaluation Board

TGA2514N-FL 13 – 18 GHz Power Amplifier

Absolute Maximum Ratings

Parameter	Value / Range
Drain Voltage (V _D)	9.0 V
Drain Current (I _D)	3.8 A
Gate Voltage Range (V _G)	-5 to 0 V
Gate Current (I _G)	-18 to +18 mA
Input Power, CW (P _{IN})	21 dBm
Power Dissipation (PDISS)	33.3 W
Operating Channel Temperature	200 °C

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

Recommended Operating Conditions

Parameter	Value / Range
Drain Voltage (V _G)	8.0 V
Gate Voltage (Vs)	-0.65 V
Drain Current (IDQ)	2.6 A
Temperature Range	−40 to +85 °C

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

Electrical Specifications

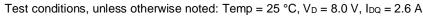
Parameter	Min	Тур	Max	Units
Frequency Range	13		16	GHz
Small Signal Gain		24		dB
Saturated Output Power		38		dBm
Input Return Loss		14		dB
Output Return Loss		14		dB

Test conditions, unless otherwise noted: Temp = 25 °C, V_D = 8.0 V, I_{DQ} = 2.6 A

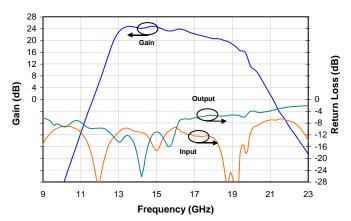
QOCVO

TGA2514N-FL 13 – 18 GHz Power Amplifier

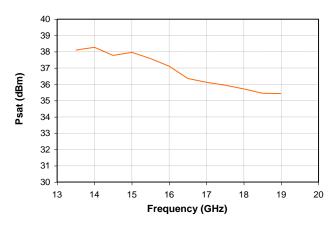
Typical Performance – Small and Large Signal



Gain and Return Loss vs. Frequency

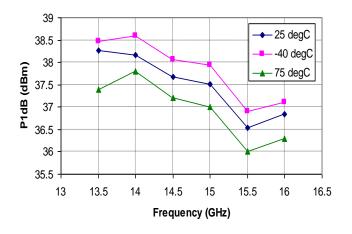


Saturated Output Power vs. Frequency



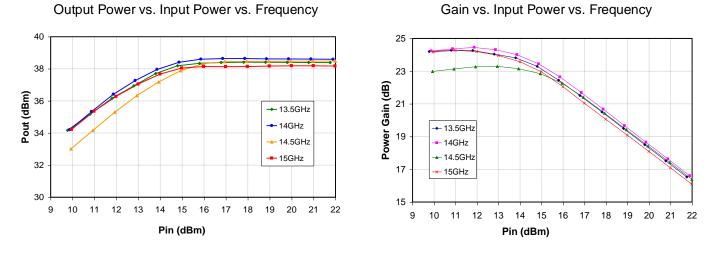
Gain vs. Frequency vs. Temperature 30 25 20 15 (dB) 10 S21 5 75 degC 0 -40 degC 25 degC -5 -10 8 10 12 14 16 18 20 22 Frequency (GHz)

P1dB vs. Frequency vs. Temperature

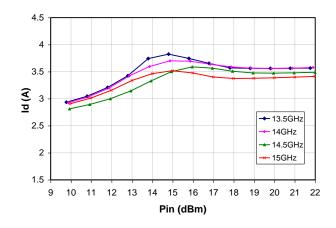


Typical Performance – Large Signal

Test conditions, unless otherwise noted: Temp = 25 °C, V_D = 8.0 V, I_{DQ} = 2.6 A



Drain Current vs. Input Power vs. Frequency



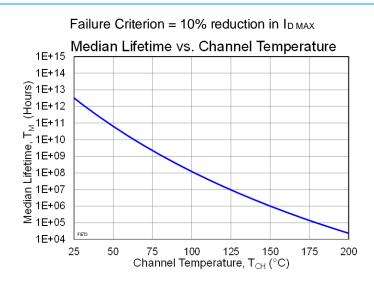
Thermal and Reliability Information

Parameter	Test Conditions	Value	Units
Thermal Resistance (θ _{JC}) ⁽¹⁾		3.9	°C/W
Channel Temperature (T _{CH}) ⁽¹⁾	$T_{BASE} = 70 \text{ °C}, V_D = 8 \text{ V} I_{DQ} = 2.6 \text{ A}, P_{DISS} = 20.8 \text{ W}$	151	°C
Median Lifetime (T _M)		9.3E5	Hrs
Thermal Resistance (θ_{JC}) ⁽¹⁾		3.9	°C/W
Channel Temperature (T _{CH}) ⁽¹⁾	$T_{BASE} = 70 \text{ °C}, V_D = 8 \text{ V} I_{DQ} = 2.6 \text{ A}, P_{DISS} = 22.5 \text{ W}$ (Under RF Drive)	158	°C
Median Lifetime (T _M)		5.2E5	Hrs

Notes:

1. Thermal resistance is referenced to the back of package (70 °C)

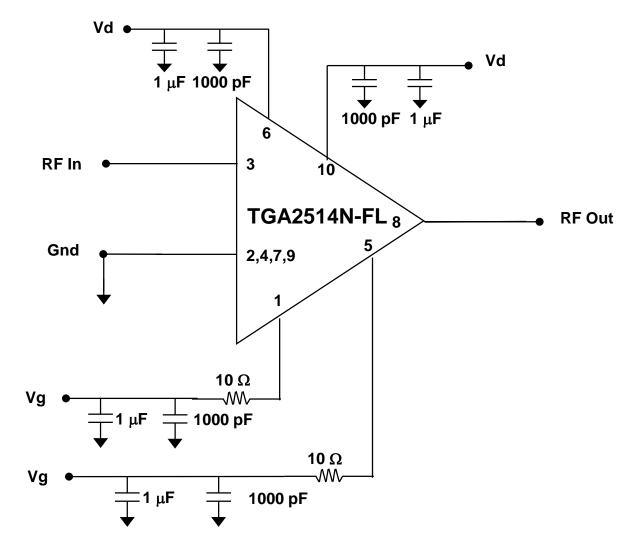
Median Lifetime





TGA2514N-FL 13 – 18 GHz Power Amplifier

Applications Circuit



Notes:

- 1. V_G can be biased from either pin 1nor pin 5.
- 2. V_D must be biased from both sides (Pins 6 and 10)

Bias Up Procedure

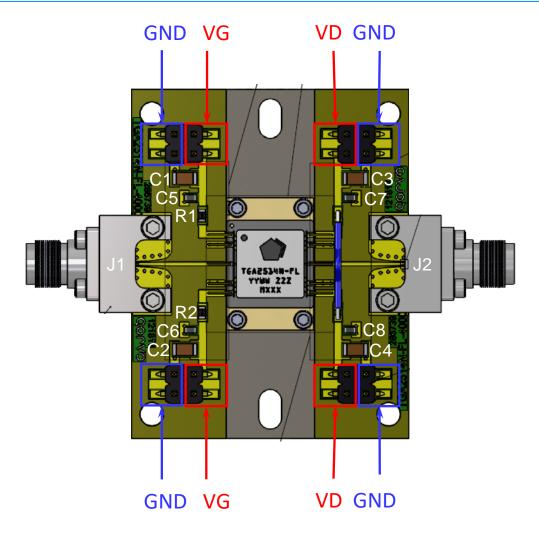
- 1. Set I_{D} limit to 3.3 A, I_{G} limit to 18 mA
- 2. Apply -1.5 V to V_G
- 3. Apply +8 V to V_D; ensure I_{DQ} is approx. 0 mA
- 4. Adjust V_G until I_{DQ} = 2.6 A (V_G ~ -0.65 V Typ.).
- 5. Turn on RF supply

Bias Down Procedure

- 1. Turn off RF supply
- 2. Reduce V_G to $-1.5\,V;$ ensure I_{DQ} is approx. 0 mA
- 3. Set V_{D} to 0 V
- 4. Turn off V_D supply
- 5. Turn off V_G supply

TGA2514N-FL 13 – 18 GHz Power Amplifier

Evaluation Board (EVB) Assembly Drawing



PCB NOTES:

1. RF Layer is 0.010" thick Rogers Corp. RO4350, εr = 3.38. Metal layers are 0.5 oz. copper. The microstrip line at the connector interface is optimized for the Southwest Microwave end launch connector 1092-01A-5.

Bill of Materials

Reference Des.	Value	Description	Manuf.	Part Number
C1, C2, C3, C4	1.0 uF	CAP, 1uF, 5% 50V, X7R, 1206	Various	-
C5, C6, C7, C8	1000 pF	CAP, 1000pF, 5%, 50V, NP0, 0603	Various	_
R1, R2	0 Ω	RES, 0 OHM, 1/10W, 0603	Various	_
J1, J2	2.92 mm	CONNECTOR, FEMALE, ENDLAUNCH	Southwest Microwave	1092-01A-5

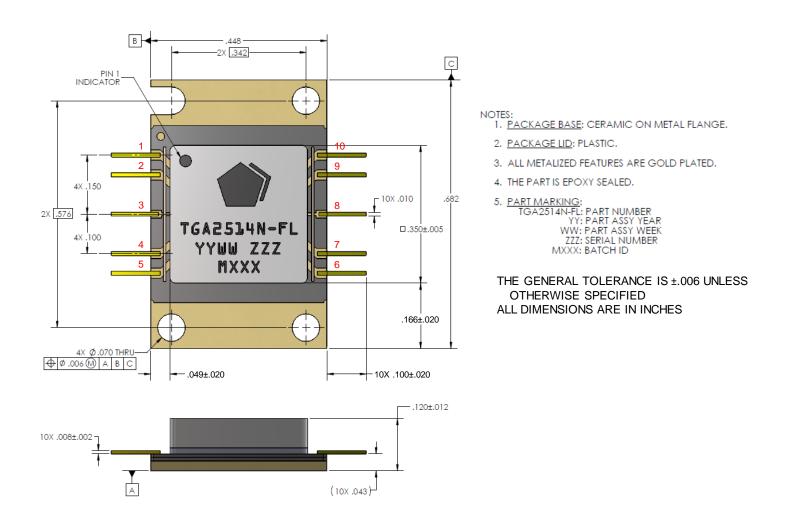
TGA2514N-FL 13 – 18 GHz Power Amplifier

Assembly Notes

- 1. Carefully clean the PC board and package leads with alcohol. Allow it to dry fully.
- 2. To improve the thermal and RF performance, Qorvo recommends attaching a heat sink to the bottom of the PCB and apply thermal compound (Arctic Silver 5 recommended) or a 4 mil indium shim between the heat sink and the package.
- 3. Apply no-flux solder to each pin of the TGA2514N-FL. The component leads should be manually soldered, and the package should not be subjected to conventional reflow processes. The use of no-clean solder to avoid washing after soldering is recommended.

TGA2514N-FL 13 – 18 GHz Power Amplifier

Mechanical Information



Pin Description

Pad No.	Symbol	Description
1,5	VG	Gate Voltage; bias network is required, part can be biased from either pin
2,4,7,9	GND	Ground
3	RF Input	RF Input; 50 Ω, AC coupled
6,10	VD	Drain Voltage; bias network is required, part must be biased from both pins
8	RF Output	RF Output; 50 Ω, AC coupled

TGA2514N-FL 13 – 18 GHz Power Amplifier

Handling Precautions

Parameter	Rating	Standard		
ESD–Human Body Model (HBM)	Class 0B	JEDEC Standard JESD22 A114		Caution! ESD-Sensitive Device
MSL-Moisture Sensitivity Level	N/A	JEDEC standard J-STD-020	JP.	

Solderability

The component leads should be manually soldered, and the package should not be subjected to conventional reflow processes. Soldering of the component leads is compatible with the latest version of J-STD-020, lead-free solder, 260 °C. The use of no-clean solder to avoid washing after soldering is recommended.

RoHS Compliance

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU. This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C15H12Br402) Free
- PFOS Free
- SVHC Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: www.qorvo.com

Tel: 1-844-890-8163

Email: customer.support@qorvo.com

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